

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

IRFU220B

• FEATURES

- With TO-251(IPAK) packaging
- Uninterruptible power supply
- · High speed switching
- · Hard switched and high frequency circuits
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

APPLICATIONS

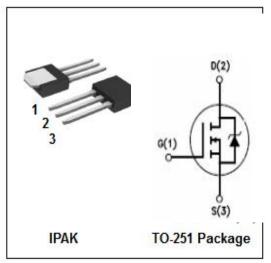
- Switching applications
- DC-DC converters
- High frequency

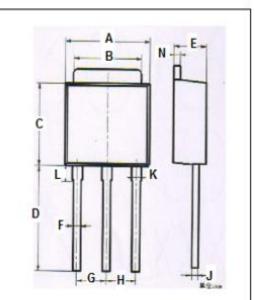
SYMBOL	PARAMETER	VALUE	UNIT					
V _{DSS}	Drain-Source Voltage	200	V					
V _{GSS}	Gate-Source Voltage	±30	V					
ID	Drain Current-Continuous@Tc=25 $^{\circ}$ CTc=100 $^{\circ}$ C	4.6 2.9	А					
I _{DM}	Drain Current-Single Pulsed	18	A					
PD	Total Dissipation	40	W					
Tj	Operating Junction Temperature	-55~150	°C					
T _{stg}	Storage Temperature	-55~150	°C					

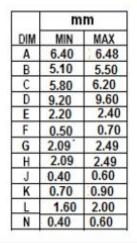
• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT		
Rth(ch-c)	Channel-to-case thermal resistance	3.14	°C /W		
Rth(ch-a)	th(ch-a) Channel-to-ambient thermal resistance		°C /W		

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isc website: www.iscsemi.cn



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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	200			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±30V; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =2.3A		0.65	0.8	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V@Tc=25°C V _{DS} =160V; V _{GS} = 0V@Tc=125°C			10 100	μA
V _{SDF}	Diode forward voltage	I _{SD} =4.6A, V _{GS} = 0 V			1.5	v

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